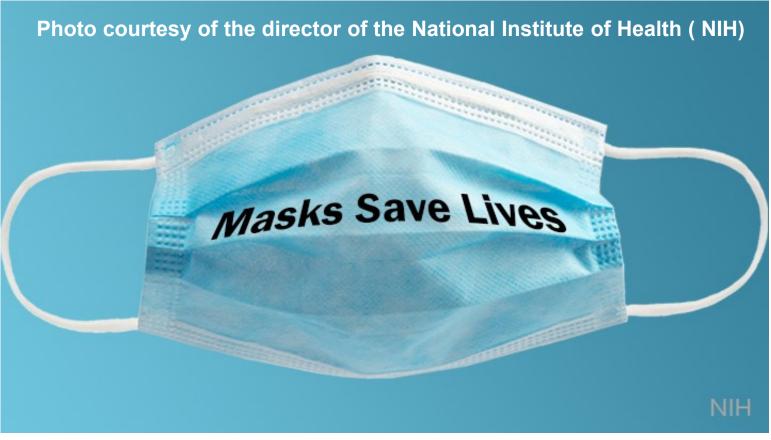
### EE 330 Lecture 5

Statistics Review (wrap up) Key Historical Developments Basic Logic Circuits



As a courtesy to fellow classmates, TAs, and the instructor

Wearing of masks during lectures and in the laboratories for this course would be appreciated irrespective of vaccination status

# **Overall Yield**

If both hard and soft faults affect the yield of a circuit, the overall yield is given by the expression

 $Y = Y_H Y_S$ 

# Cost Per Good Die

The manufacturing costs per good die is given by

$$C_{Good} = \frac{C_{FabDie}}{Y}$$

where  $C_{FabDie}$  is the manufacturing costs of a fab die and Y is the yield

There are other costs that must ultimately be included such as testing costs, engineering costs, etc.

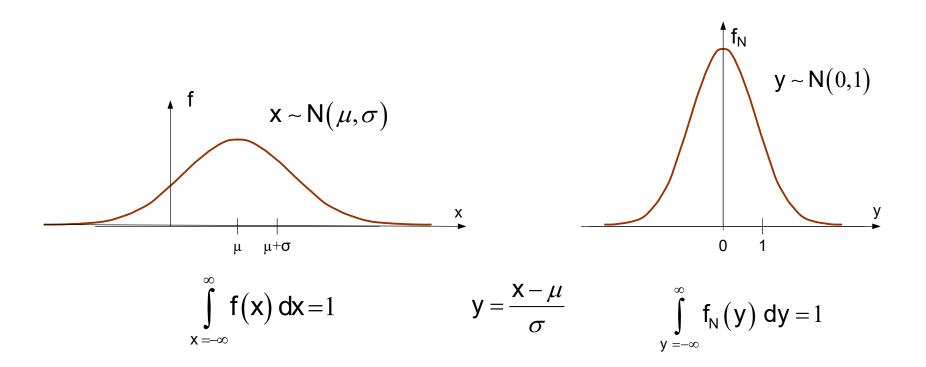
# **Statistics are Real!**

Statistics govern what really happens throughout much of the engineering field!

### Statistics are your Friend !!!!

You might as well know what will happen since statistics characterize what WILL happen in the presence of variability in many processes !

### **Statistics Review**



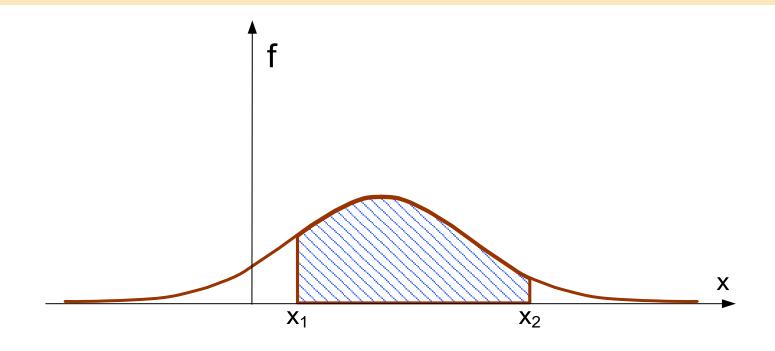
Theorem 1: If the random variable x in normally distributed with mean  $\mu$  and standard deviation  $\sigma$ , then  $y = \frac{x - \mu}{\sigma}$  is also a random variable that is normally distributed with mean 0 and standard deviation of 1.

(Normal Distribution and Gaussian Distribution are the same)

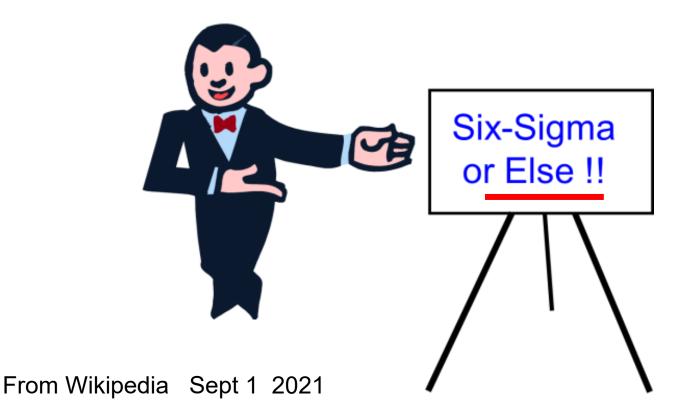
#### Review from Last Lecture Background Information

Theorem 2: If x is a Normal (Gaussian) random variable with mean  $\mu$  and standard deviation  $\sigma$ , then the probability that x is between  $x_1$  and  $x_2$  is given by

$$p = \int_{x_1}^{x_2} f(x) dx = \int_{x_{1n}}^{x_{2n}} f_n(x) dx \quad \text{where} \quad x_{1n} = \frac{x_1 - \mu}{\sigma} \quad \text{and} \quad x_{2n} = \frac{x_2 - \mu}{\sigma}$$
  
and where  $f_n(x)$  is N(0,1)



## Many Companies Promote the Real Six-Sigma Challenge

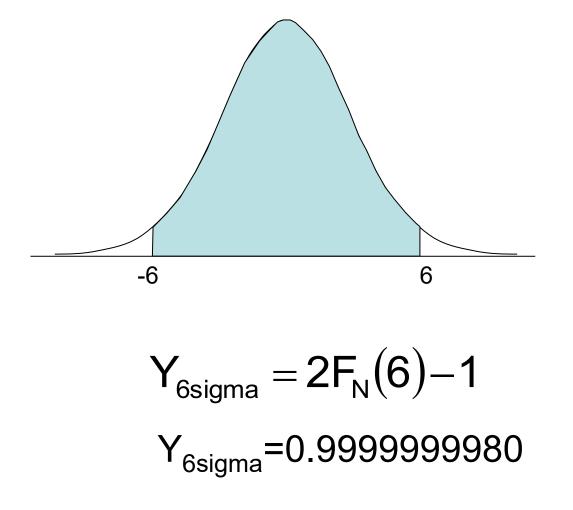


In 2005 Motorola attributed over \$17 billion in savings to Six Sigma.<sup>[3]</sup>

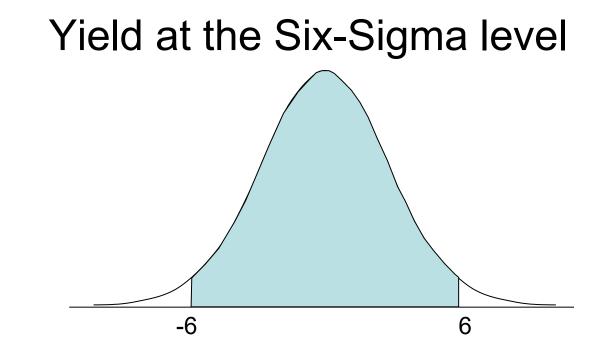
By the late 1990s, about two-thirds of the <u>Fortune 500</u> organizations had begun Six Sigma initiatives with the aim of reducing costs and improving quality.<sup>[6]</sup>

#### Review from Last Lecture Yield at the Six-Sigma level

(Assume a Gaussian distribution)



This is approximately 2 defects out of 1 billion parts



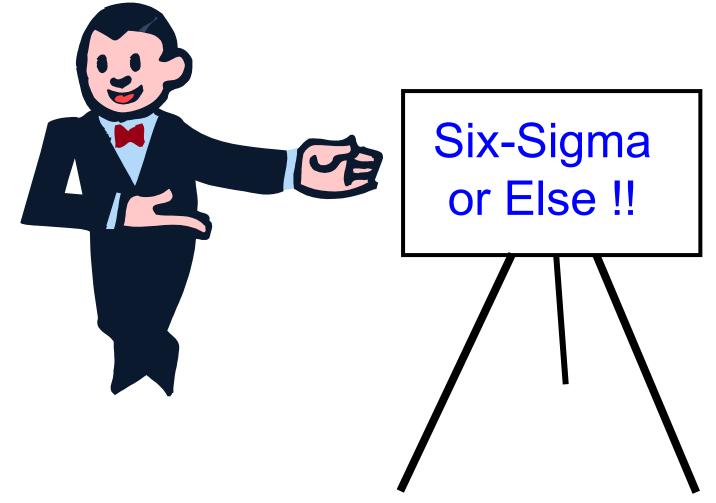
This is approximately 2 defects out of 1 billion parts

Would producing ICs with a yield at the six-sigma level be a good goal?

How about smart phones with defects at this level? (approx. 1.4B sold in 2020)

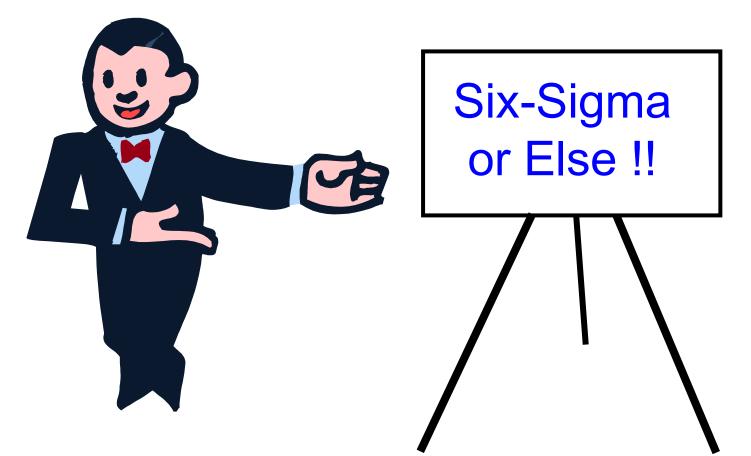
How about automobiles? (approx. 78 million produced in 2020)

### Meeting the Real Six-Sigma Challenge



**Highly Statistical Concept !** 

### Meeting the Real Six-Sigma Challenge



#### Review from Last Lecture Six-Sigma or Else !!

How serious is the "or Else" in the six-sigma programs?



# Meeting the Real Six-Sigma Challenge



How has Motorola fared with the 6-sigma approach?



	Former type	Public company
	Industry	Telecommunications
	Fate	Divided into Motorola Mobility and Motorola Solutions
	Successor	Motorola Mobility Motorola Solutions
	Founded	September 25, 1928
<	Defunct	January 4, 2011

- Sold military activities to General Dynamics 2000/2001
- Sold automotive products in 2006
- Spun of discrete components as ON semiconductor in 1999
- Spun of SPS as Freescale in 2003 Acquired by NXP in 2015
- Sold Motorola Mobility to Google in 2011 Acquired by Lonovo in 2014
- Motorola Solutions has 16,000 employees (ref fall 2018), down from over 150,000 in mid '90s

# Statistics can be abused !

Many that are not knowledgeable incorrectly use statistics

Many use statistics to intentionally mislead the public

Some openly abuse statistics for financial gain or for manipulation purposes

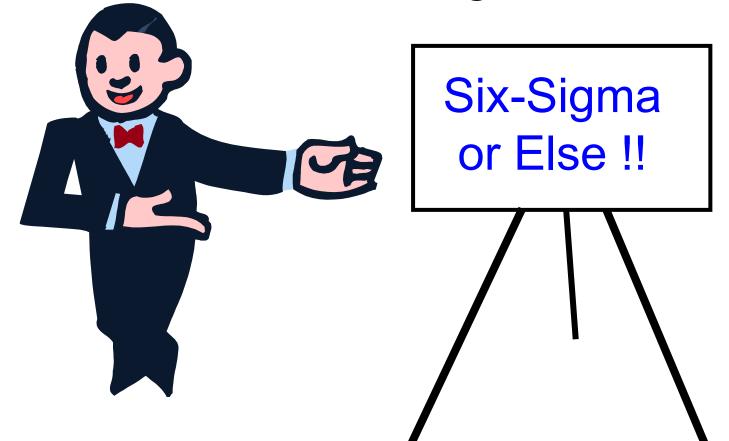
Keep an open mind to separate "good" statistics from "abused" statistics

Example: This was part of an article that appeared on Jan 26, 2022. The content of the article is not relevant but rather it serves as an example of use of statistics in our society

The Washington Post in 2018 reported the statistical likelihood of a public school student in the US being killed by gunfire at school was roughly 1 in 614,000,000 since 1999.

### Is this an abuse of statistics?

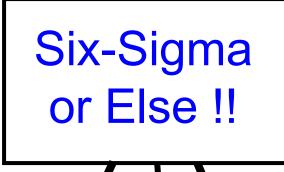
### Meeting the Real Six-Sigma Challenge



Six-sigma capability has almost nothing to do with optimizing profits and, if taken seriously, will likely guarantee a financial fiasco in most manufacturing processes



### Meeting the real Six-Sigma Challenge





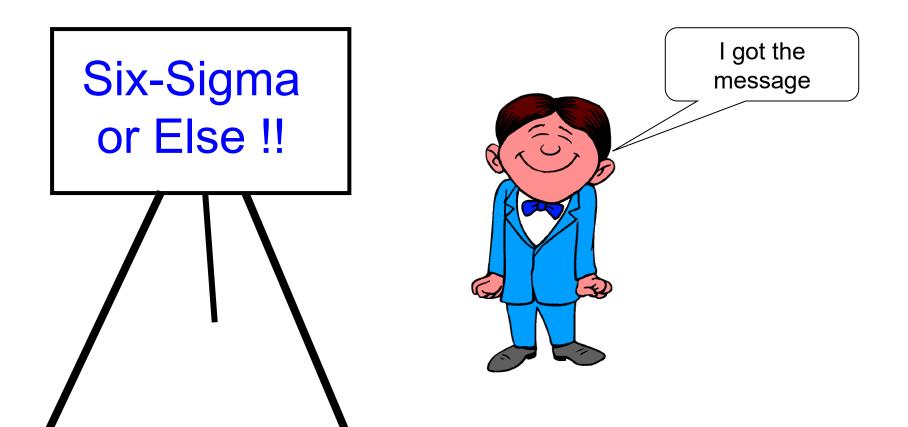
### Meeting the real Six-Sigma Challenge

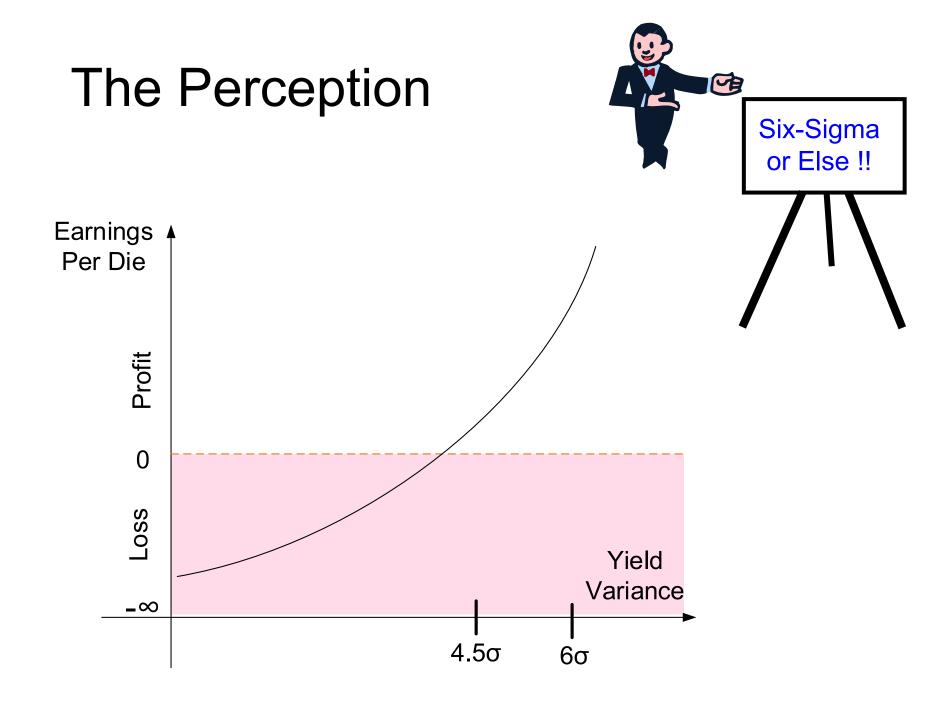
Six-Sigma or Else !!

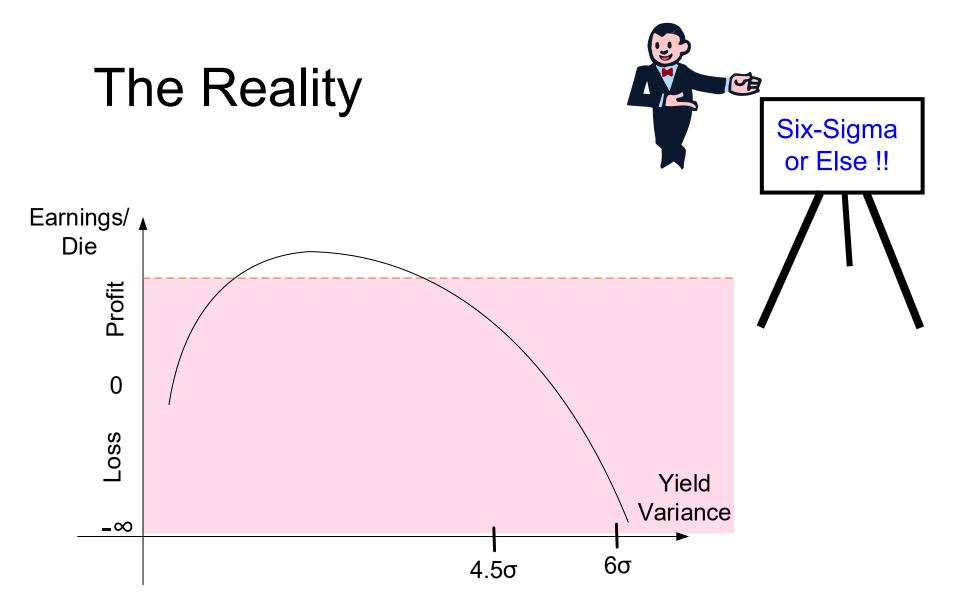


The concept of improving reliability (really profitability) is good – its just the statistics that are abused!

### Meeting the real Six-Sigma Challenge

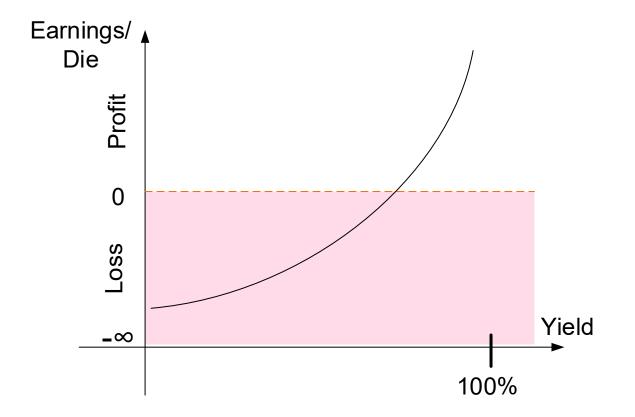






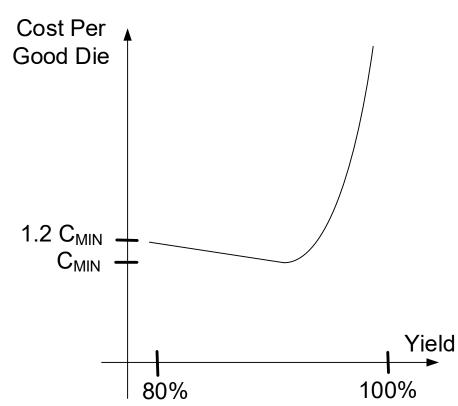
- Designing for 4.5σ or 6σ yield variance will almost always guarantee large losses
- Yield targets should be established to optimize earnings not yield variance

### The Perception on Yield



Perception is often that goal should be to get yields as close to 100% as possible

### The Reality about Yield



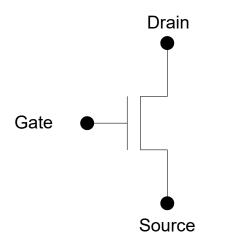
- Return on improving yield when yield is above 95% is small
- Inflection point could be at 99% or higher for some designs but below 50% for others
- Cost/good die will ultimately go to  $\infty$  as yield approaches 100%

#### Designers goal should be to optimize profit, not an arbitrary yield target

# Key Historical Developments

- 1925,1935 Concept of MOS Transistor Proposed (Lilienfield and Heil)
- 1947 BJT Conceived and Experimentally Verified (Bardeen, Bratin and Shockley of Bell Labs)
- 1959 Jack Kilby (TI) and Bob Noyce (Fairchild) invent IC
- 1963 Wanless (Fairchild) Experimentally verifies MOS Gate

### The MOS Transistor (Field Effect Transistor)



### Initially an idea but little more !

#### 1926 - Field Effect Semiconductor Device Concepts Patented

Julius Lilienfeld files a patent describing a three-electrode amplifying device based on the semiconducting properties of copper sulfide. Attempts to build such a device continue through the 1930s.



Julius E. Lilienfeld, passport photo

Polish-American physicist and inventor Julius E. Lilienfeld filed a patent in 1926, "Method and Apparatus for Controlling Electric Currents," in which he proposed a three-electrode structure using copper-sulfide semiconductor material. Today this device would be called a field-effect transistor. While working at Cambridge University in 1934, German electrical engineer and inventor Oskar Heil filed a patent on controlling current flow in a semiconductor via capacitive coupling at an electrode – essentially a field-effect transistor. Although both patents were granted, no records exist to prove that Heil or Lilienfeld actually constructed functioning devices.

Lilienfeld, J. E. "Method and apparatus for controlling electric currents," *U. S. Patent No. 1,745,175* (Filed October 8, 1926. Issued January 18, 1930). Lilienfeld, J. E. "Device for controlling electric current," *U. S. Patent No. 1,900,018* (Filed March 28, 1928. Issued March 7, 1933).

Heil, O. "Improvements in or relating to electrical amplifiers and other control arrangements and devices," *British Patent No. 439, 457* (Filed March 5, 1935. Issued December 6, 1935).

#### 1935 Oskar Heil improved MOSFET



#### From Wilipedia:

**Oskar Heil** (20 March 1908, in <u>Langwieden</u> – 15 May 1994, <u>San Mateo, California</u>) was a <u>German</u> electrical engineer and inventor. He studied <u>physics</u>, <u>chemistry</u>, <u>mathematics</u>, and <u>music</u> at the <u>Georg-August University of</u> <u>Göttingen</u> and was awarded his <u>PhD</u> in 1933, for his work on molecular spectroscopy.

Lilienfeld, J. E. "Method and apparatus for controlling electric currents," *U. S. Patent No. 1,745,175* (Filed October 8, 1926. Issued January 18, 1930). Lilienfeld, J. E. "Device for controlling electric current," *U. S. Patent No. 1,900,018* (Filed March 28, 1928. Issued March 7, 1933).

Heil, O. "Improvements in or relating to electrical amplifiers and other control arrangements and devices," *British Patent No. 439, 457* (Filed March 5, 1935. Issued December 6, 1935).

https://www.google.com/search?q=Oskar+Heil&biw=1097&bih=568&tbm=isch&imgil=19nt7iXoiQ-

X0M%253A%253B8o3VY91vkR5qnM%253Bhttp%25253A%25252F%25252Fwww.avguide.ch%25252Fmagazin%25252Flautsprecher-made-in-ticino-martin-duerrenmattperfektioniert-den-heil&source=iu&pf=m&fir=19nt7iXoiQ-X0M%253A%252C8o3VY91vkR5qnM%252C\_&usg=\_\_67U7QCOIp8tsrLWv8y\_YzTy9c7I%3D#imgrc=dv9icif2DsZ0M%3A&usg=\_\_67U7QCOIp8tsrLWv8y\_YzTy9c7I%3D

http://www.computerhistory.org/semiconductor/timeline/1926-field.html

#### UNITED STATES PATENT OFFICE

JULIUS EDGAB LILIENFELD, OF BROOKLYN, NEW YORK METHOD AND APPARATUS FOR CONTROLLING FLECTRIC CURRENTS Application filed October 8, 1926, Serial No. 140,363, and in Canada October 22, 1925.

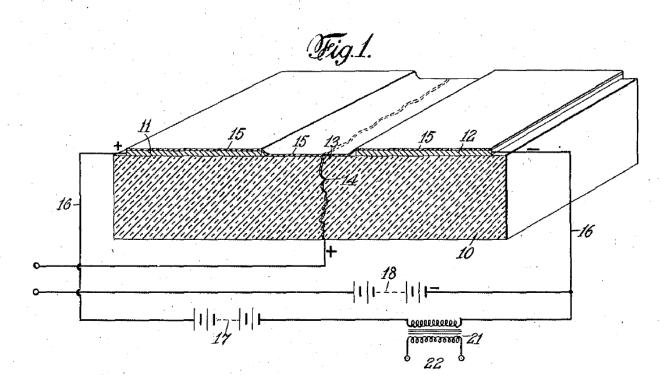
Jan. 28, 1930.

J. E. LILIENFELD

1,745,175

METHOD AND APPARATUS FOR CONTROLLING ELECTRIC CURRENTS

Filed Oct. 8, 1926



#### March 7, 1933.

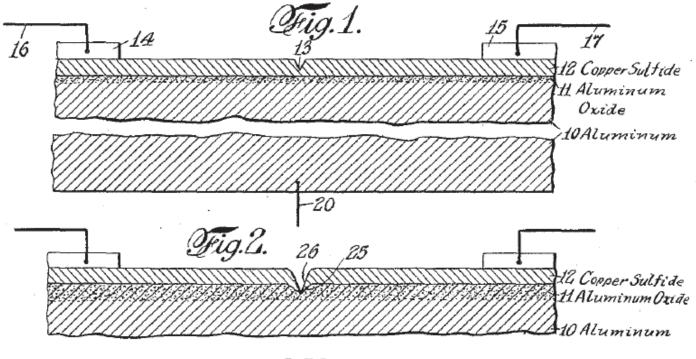
#### J. E. LILIENFELD

#### 1,900,018

#### DEVICE FOR CONTROLLING ELECTRIC CURRENT

Filed March 28, 1928

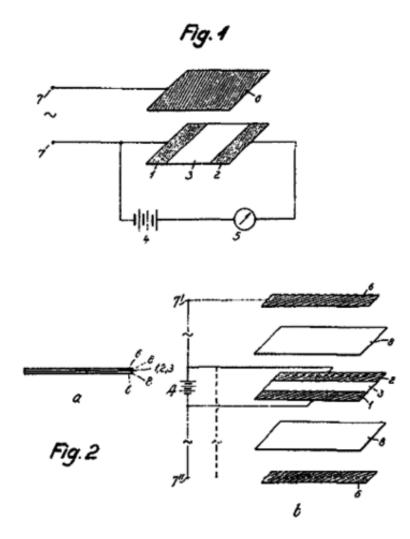
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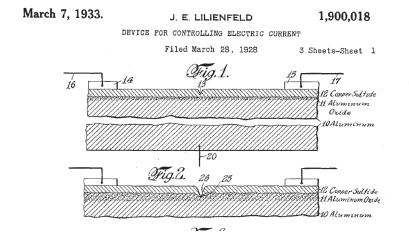
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#### Figures from Heil 1935 patent

Insulated gate controls field between other two terminals



# Though a great idea, of little consequence since couldn't make them!



#### Was there an alternative?

Yes - A relatively new technology – the vacuum tube!

### The Vacuum Tube Era

#### 1910 to 1970



The vacuum tube (invented in 1910)

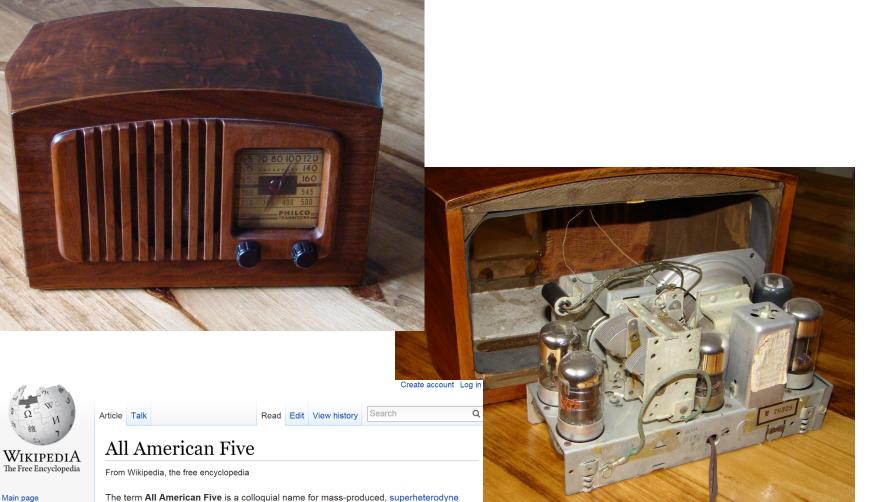
- A major breakthrough in electronics technology
- 6+ decade life span
- Vacuum tube systems not readily affordable by all of society
- Heavy, hot, expensive, large, poor reliability, fragile

### The 5-Tube am radio





### The 5-Tube am radio



The term **All American Five** is a colloquial name for mass-produced, superheterodyne radio receivers that used five vacuum tubes in their design. These radio sets were designed to receive amplitude modulation (AM) broadcasts in the medium wave band, and were manufactured in the United States from the mid-1930s until the early 1960s<sup>[1]</sup> By

Contents

Featured content

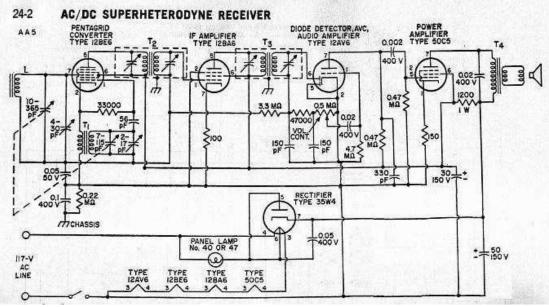
Current events

Bandana antara

### The 5-Tube am radio



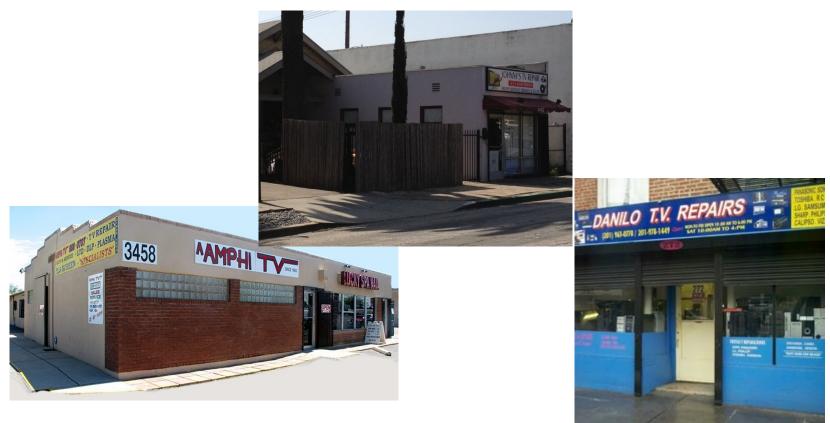
(pictures from WEB pages of images)



Schematics were simple !!

## The Vacuum Tube Era

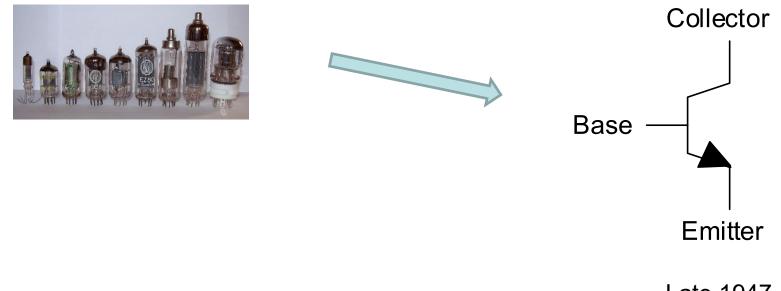
Lots of people supported the industry (primarily radio, later radio and TV) with repair shops throughout the country

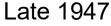


(pictures from WEB pages of companies)

Tubes as well as resistors and capacitors had poor reliability

### The Bipolar Transistor (Bipolar Junction Transistor – BJT)



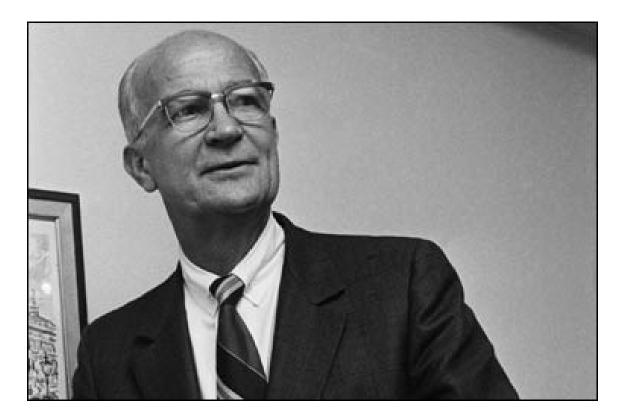


A solution to a major bottleneck limiting the development of electronics technology !

## Naming the Transistor

From the group at Bell Labs

"We have called it the transistor, T-R-A-N-S-I-S-T-O-R, because it is resistor or semiconductor device which can amplify electrical signals as they are transferred through it from input to output terminals. It is, if you will, the electrical equivalent of a vacuum tube amplifier. But there the similarity ceases. It has no vacuum, no filament, no glass tube. It is composed entirely of cold, solid substances."



William Shockley

http://www.time.com/time/time100/scientist/profile/shockley03.html

### William Shockley

He fathered the transistor and brought the silicon to Silicon Valley but is remembered by many only for his noxious racial views By GORDON MOORE



Gordon Moore

The transistor was born just before Christmas 1947 when John Bardeen and Walter Brattain, two scientists working for William Shockley at Bell Telephone Laboratories in Murray Hill, N.J., observed that when electrical signals were applied to contacts on a crystal of germanium, the output power was larger than the input. Shockley was not present at that first observation. And though he fathered the discovery in the same way Einstein fathered the atom bomb, by advancing the idea and pointing the way, he felt left out of the momentous occasion.

Shockley, a very competitive and sometimes infuriating man, was determined to make his imprint on the discovery. He searched for an explanation of the effect from what was then known of the quantum physics of semiconductors. In a remarkable series of insights made over a few short weeks, he greatly extended the understanding of semiconductor materials and developed the underlying theory of another, much more robust amplifying device — a kind of sandwich made of a crystal with varying impurities added, which came to be known as the junction transistor. By 1951 Shockley's co-workers made his semiconductor sandwich and demonstrated that it behaved much as his theory had predicted.

Not content with his lot at Bell Labs, Shockley set out to capitalize on his invention. In doing so, he played a key role in the industrial development of the region at the base of the San Francisco Peninsula. It was Shockley who brought the silicon to Silicon Valley.

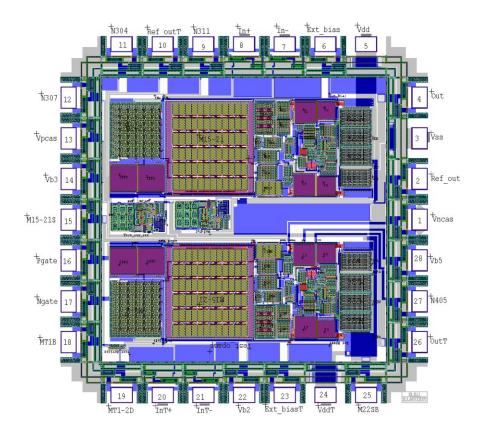
In February 1956, with financing from Beckman Instruments Inc., he founded Shockley Semiconductor Laboratory with the goal of developing and producing a silicon transistor. He chose to establish this start-up near Palo Alto, where he had grown up and where his mother still lived. He set up operations in a storefront — little more than a Quonset hut — and hired a group of young scientists (I was one of them) to develop the necessary technology. By the spring of 1956 he had a small staff in place and was beginning to undertake research and development.

.... (in early 1957 a group of the key people involved with Shockley left and formed a new company named Fairchild Semiconductor ...) This new company, financed by Fairchild Camera & Instrument Corp., became the mother organization for several dozen new companies in Silicon Valley. Nearly all the scores of companies that are or have been active in semiconductor technology can trace the technical lineage of their founders back through Fairchild to the Shockley Semiconductor Laboratory. Unintentionally, Shockley contributed to one of the most spectacular and successful industry expansions in history. *Editor's note:* 

In 1963 Shockley left the electronics industry and accepted an appointment at Stanford. There he became interested in the origins of human intelligence. Although he had no formal training in genetics or psychology, he began to formulate a theory of what he called dysgenics. Using data from the U.S. Army's crude pre-induction IQ tests, he concluded that African Americans were inherently less intelligent than Caucasians — an analysis that stirred wide controversy among laymen and experts in the field alike.

(Fairchild was formed in 1957 – Moore and Noyce were 2 of 8 co-founders)

## The Integrated Circuit



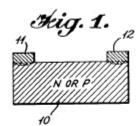


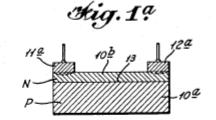


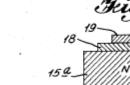
MINIATURIZED ELECTRONIC CIRCUITS

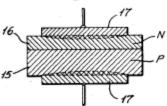
Filed Feb. 6, 1959

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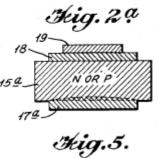


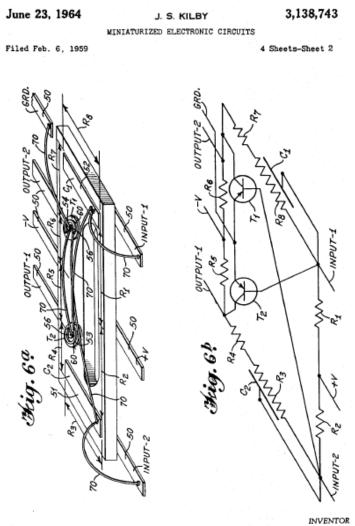






Hig. 2.





Jack S. Kilby

BY Stevens, Davis, Willow & Mosker ATTORNEYS

### United States Patent BEST AVAILABLE COPY

### Kilby

### [45] Feb. 15, 1972

[15]

3,643,138

#### [54] SEMICONDUCTOR DEVICE

#### Peterson and Stevens, Davis, Miller and Mosher

### [72] Inventor: Jack St. Clair Kliby, Dallas, Tex.

[73] Assignee: Texas Instruments Incorporated, Dallas, Tex.

- [22] Filed: Jan. 29, 1962
- [21] Appl. No.: 169,557

#### **Related U.S. Application Data**

[63] Continuation-in-part of Ser. No. 791,602, Feb. 6, 1959, Pat. No. 3,138,743, and a continuation-in-part of 811,476, May 6, 1959, abandoned, and a continuation-in-part of 811,486, May 6, 1959, Pat. No. 3,138,744.

[52]	U.S. Cl.	
[51]	Int. Cl.	
1581	Field of Search	

#### [56] References Cited

#### UNITED STATES PATENTS

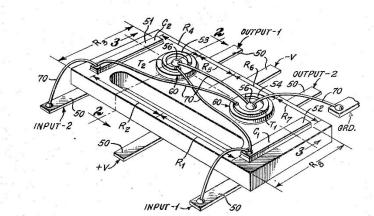
2.680.220	6/1954	Starr et al
2,709,232	5/1955	Thedieck
2,792,538	5/1957	Pfann
2,796,562	6/1957	Ellis et al
2,890,395	6/1959	Lathrop et al
2,910,634	10/1959	Rutz
3,038,085	6/1962	Wallmark et al

Primary Examiner-James D. Kallam

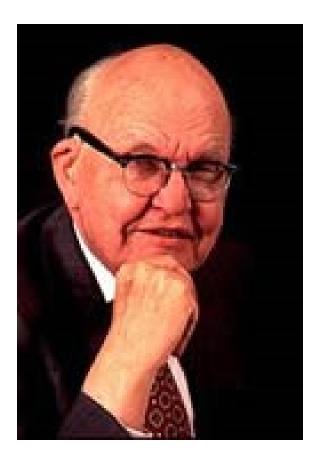
Attorney-James O. Dixon, Andrew M. Hassell, Robert C.

- 1. A semiconductor device comprising:
- a. a wafer of semiconductor material having two major faces;
  b. said wafer being so shaped as to define a plurality of
- b. said water being so snaped as to define a pluraity of regions within said wafer and adjacent to one of said major faces;
- c. at least some of said regions being electrically isolated within said wafer from others of said regions;
- d. said regions having at least one portion thereof extending to said one major face;
- e. at least some of said portions having selected locations on said one major face for electrical contact to said region;
- f. an insulating material on said one major face of the wafer excluding at least said selected locations;
- g. at least one electrically conductive area in contact with said insulating material and spaced from said wafer thereby;
- h. said electrically conductive area being disposed in cooperative relationship with respect to a selected one of said isolated regions so as to provide the electrical function of a discrete electrical circuit component: and
- a plurality of metallic interconnections providing electrically conductive paths between said selected locations on different ones of said regions and between another selected one of said locations and said electrically conductive area.

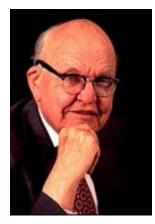
4 Claims, 33 Drawing Figures



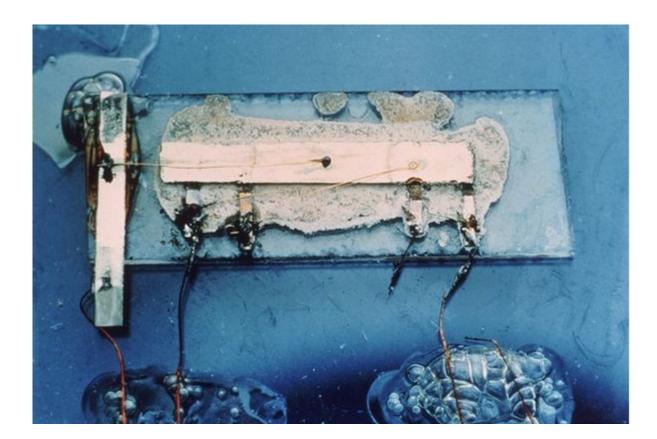
Stevens, Davis, Miller and Mosh EXEMPLARY CLAIM



Jack Kilby



Jack Kilby



Kilby's Integrated Circuit (germanium)

http://www.ti.com/corp/docs/kilbyctr/jackstclair.shtml There are few men whose insights and professional accomplishments have changed the world. Jack Kilby is one of these men. His invention of the monolithic integrated circuit - the microchip - some 45 years ago at Texas Instruments (TI) laid the conceptual and technical foundation for the entire field of modern microelectronics. It was this breakthrough that made possible the sophisticated high-speed computers and large-capacity semiconductor memories of today's information age.

Mr. Kilby grew up in Great Bend, Kansas. With B.S. and M.S. degrees in electrical engineering from the Universities of Illinois and Wisconsin respectively, he began his career in 1947 with the Centralab Division of Globe Union Inc. in Milwaukee, developing ceramic-base, silk-screen circuits for consumer electronic products.

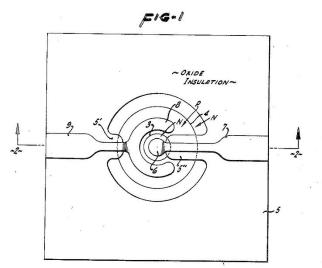
In 1958, he joined TI in Dallas. During the summer of that year working with borrowed and improvised equipment, he conceived and built the first electronic circuit in which all of the components, both active and passive, were fabricated in a single piece of semiconductor material half the size of a paper clip. The successful laboratory demonstration of that first simple microchip on September 12, 1958, made history.

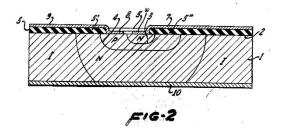
Jack Kilby went on to pioneer military, industrial, and commercial applications of microchip technology. He headed teams that built both the first military system and the first computer incorporating integrated circuits. He later co-invented both the hand-held calculator and the thermal printer that was used in portable data terminals.

#### April 25, 1961 2,981,877 R. N. NOYCE

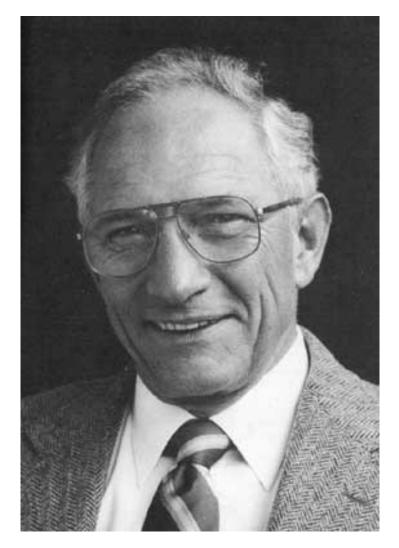
SEMICONDUCTOR DEVICE-AND-LEAD STRUCTURE Filed July 30, 1959

3 Sheets-Sheet 1





INVENTOR. ROBER N. NOYCE ATTORNEYS



Robert Noyce

http://www.ideafinder.com/history/inventors/noyce.htm

Robert Norton Noyce was born December 12, 1927 in Burlington, Iowa. A noted visionary and natural leader, Robert Noyce helped to create a new industry when he developed the technology that would eventually become the microchip. Noted as one of the original computer entrepreneurs, he founded two companies that would largely shape today's computer industry—Fairchild Semiconductor and Intel.

Bob Noyce's nickname was the "Mayor of Silicon Valley." He was one of the very first scientists to work in the area -- long before the stretch of California had earned the Silicon name -- and he ran two of the companies that had the greatest impact on the silicon industry: Fairchild Semiconductor and Intel. He also invented the integrated chip, one of the stepping stones along the way to the microprocessors in today's computers.

Noyce, the son of a preacher, grew up in Grinnell, Iowa. He was a physics major at Grinnell College, and exhibited while there an almost baffling amount of confidence. He was always the leader of the crowd. This could turn against him occasionally -- the local farmers didn't approve of him and weren't likely to forgive quickly when he did something like steal a pig for a college luau. The prank nearly got Noyce expelled, even though the only reason the farmer knew about it was because Noyce had confessed and offered to pay for it. While in college, Noyce's physics professor Grant Gale got hold of two of the very first transistors ever to come out of Bell Labs. Gale showed them off to his class and Noyce was hooked. The field was young, though, so when Noyce went to MIT in 1948 for his Ph.D., he found he knew more about transistors than many of his professors.

After a brief stint making transistors for the electronics firm Philco, Noyce decided he wanted to work at Shockley Semiconductor. In a single day, he flew with his wife and two kids to California, bought a house, and went to visit Shockley to ask for a job -- in that order.

As it was, Shockley and Noyce's scientific vision -- and egos -clashed. When seven of the young researchers at Shockley semiconductor got together to consider leaving the company, they realized they needed a leader. All seven thought Noyce, aged 29 but full of confidence, was the natural choice. So Noyce became the eighth in the group that left Shockley in 1957 and founded Fairchild Semiconductor.

Noyce was the general manager of the company and while there invented the integrated chip -- a chip of silicon with many transistors all etched into it at once. Fairchild Semiconductor filed a patent for a semiconductor integrated circuit based on the planar process on July 30, 1959. That was the first time he revolutionized the semiconductor industry. He stayed with Fairchild until 1968, when he left with Gordon Moore to found Intel. At Intel he oversaw Ted Hoff's invention of the microprocessor -- that was his second revolution.

At both companies, Noyce introduced a very casual working atmosphere, the kind of atmosphere that has become a cultural stereotype of how California companies work. But along with that open atmosphere came responsibility. Noyce learned from Shockley's mistakes and he gave his young, bright employees phenomenal room to accomplish what they wished, in many ways defining the Silicon Valley working style was his third revolution. The key patents that revolutionized the electronics field:

Jack Kilby (34 years old at invention) patent: 3,138,743

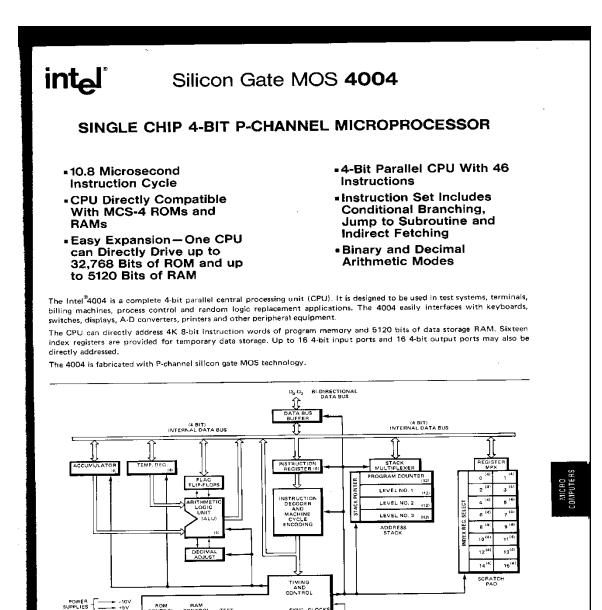
Filed Feb 6, 1959

Issued June 23, 1964

Robert Noyce (31 years old at invention)patent: 2,981,877FiledJuly 30, 1959Issued April 25, 1961

## Key Historical Developments

 1971 Intel Introduces 4004 microprocessor (2300 transistors, 10u process)



SYNC CLOCK

SYNG OT UZ RESET

RAM CONTROL

CM RAM 0.3

11

TEST

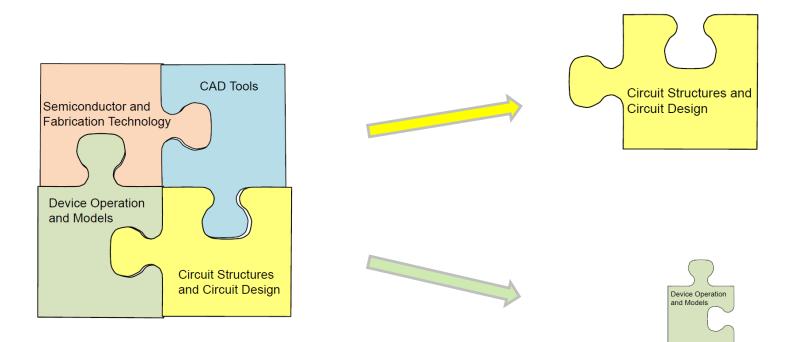
TEST

ROM CONTROL

CM ROM

6.5

# **Basic Logic Circuits**



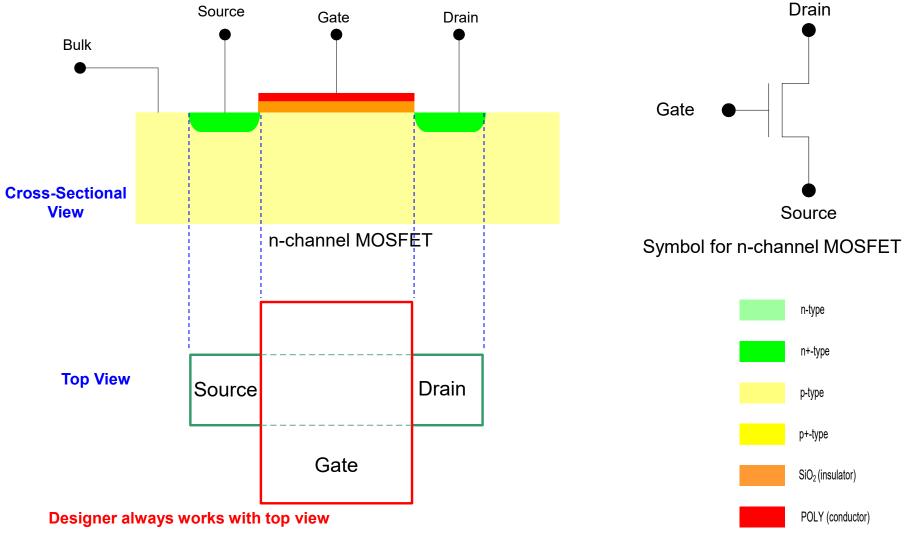
# **Basic Logic Circuits**

- Will present a brief description of logic circuits based upon simple models and qualitative description of processes
- Will later discuss process technology needed to develop better models
- Will even later provide more in-depth discussion of logic circuits based upon better device models

## Models of Devices

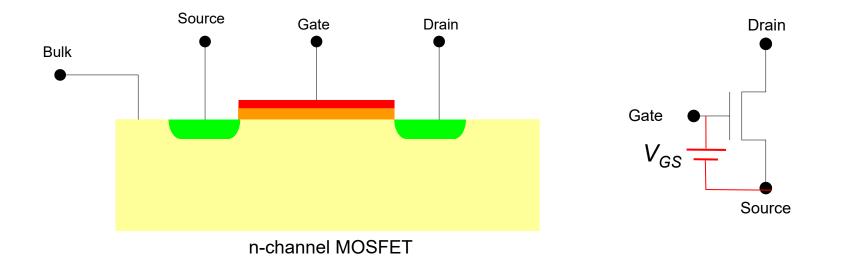
- Several models of the electronic devices will be introduced throughout the course
  - Complexity
  - Accuracy
  - Insight
  - Application
- Will use the simplest model that can provide acceptable results for any given application

## MOS Transistor Qualitative Discussion of n-channel Operation



**Complete Symmetry in construction between Drain and Source** 

## MOS Transistor Qualitative Discussion of n-channel Operation

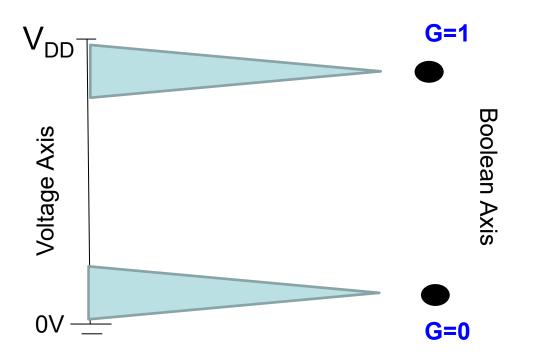


Behavioral Description of Operation of n-channel MOS Transistors Created for use in Basic Digital Circuits

If V<sub>GS</sub> is large, short circuit exists between drain and source

If V<sub>GS</sub> is small (or negative), open circuit exists between drain and source

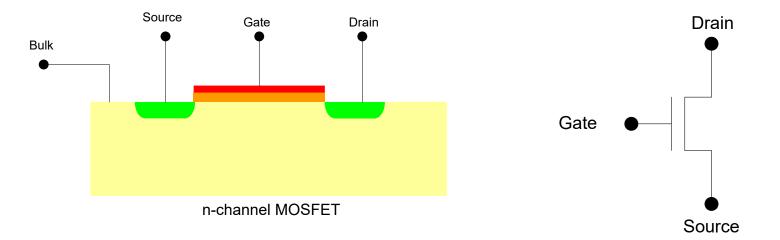
### **Boolean/Continuous Notation:**



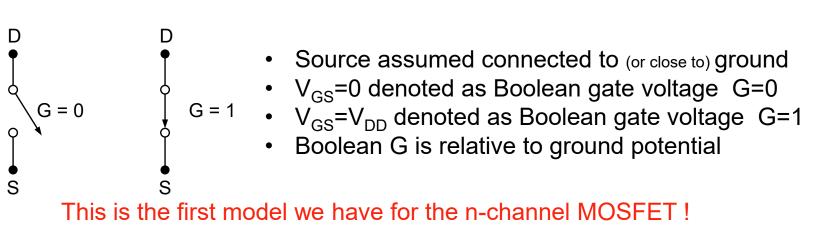
Voltage Axis is Continuous between 0V and V<sub>DD</sub>
 Boolean axis is discrete with only two points

Most logic circuits characterized by the relationship between the Boolean input/output variables though these correspond to voltage intervals on the continuous voltage axis

## MOS Transistor Qualitative Discussion of n-channel Operation

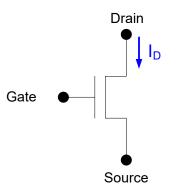


### Equivalent Circuit for n-channel MOSFET

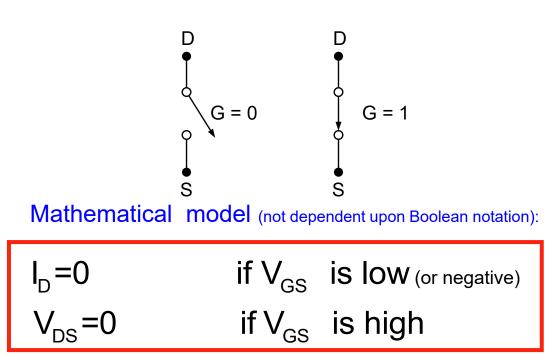


Ideal switch-level model

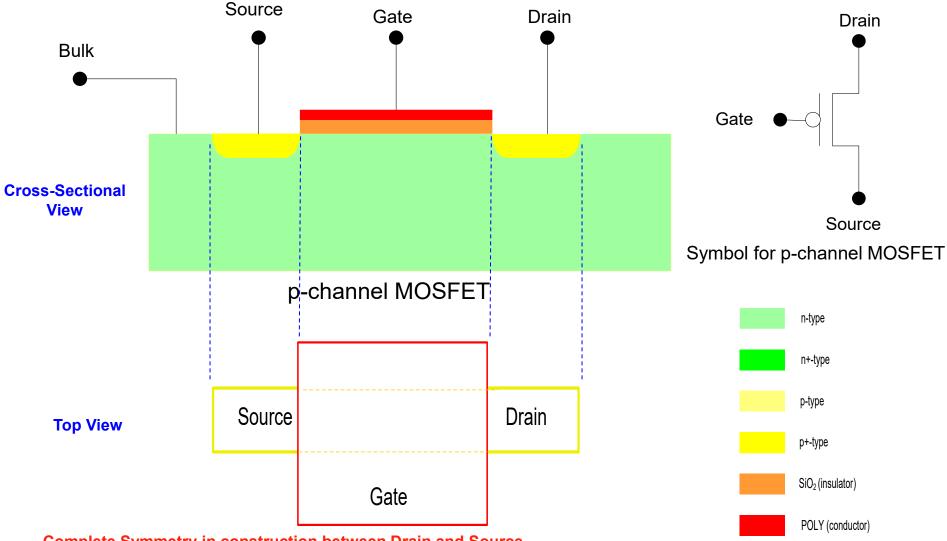
## **MOS Transistor MODEL**



Equivalent Circuit for n-channel MOSFET with source at ground

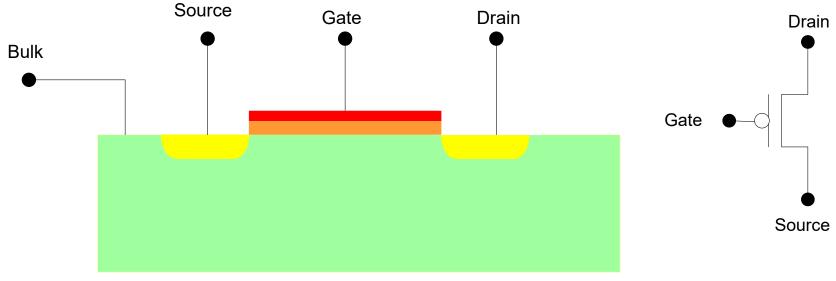


## MOS Transistor Qualitative Discussion of p-channel Operation



**Complete Symmetry in construction between Drain and Source** 

## MOS Transistor Qualitative Discussion of p-channel Operation



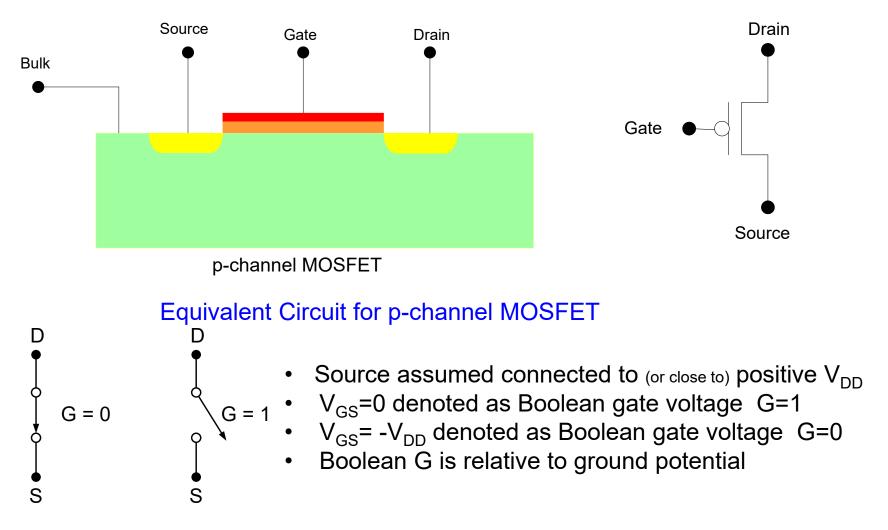
p-channel MOSFET

Behavioral Description of Operation of p-channel transistors created for use in basic digital circuits

If V<sub>GS</sub> is large (and negative), short circuit exists between drain and source

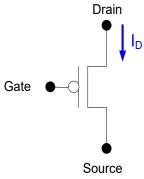
If V<sub>GS</sub> is small (near 0 or positive), open circuit exists between drain and source

## MOS Transistor Qualitative Discussion of p-channel Operation

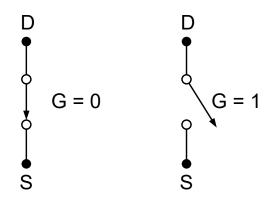


This is the first model we have for the p-channel MOSFET!

## **MOS Transistor MODEL**



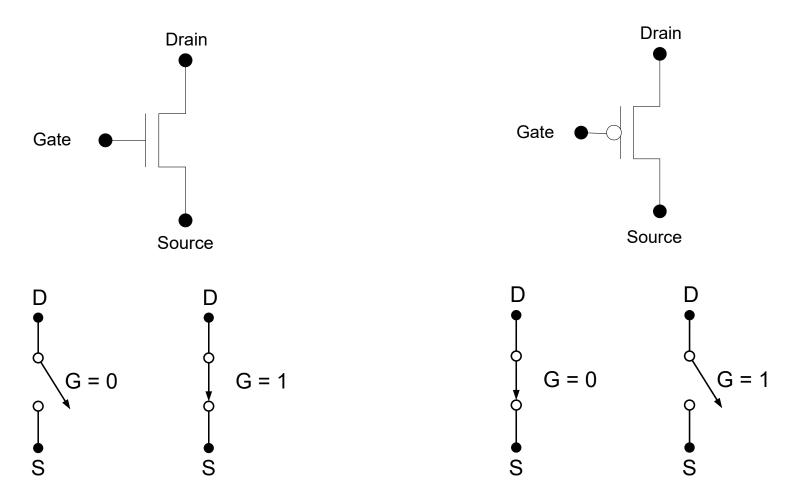
Equivalent Circuit for p-channel MOSFET with Source at VDD



Mathematical model (not dependent upon Boolean notation):

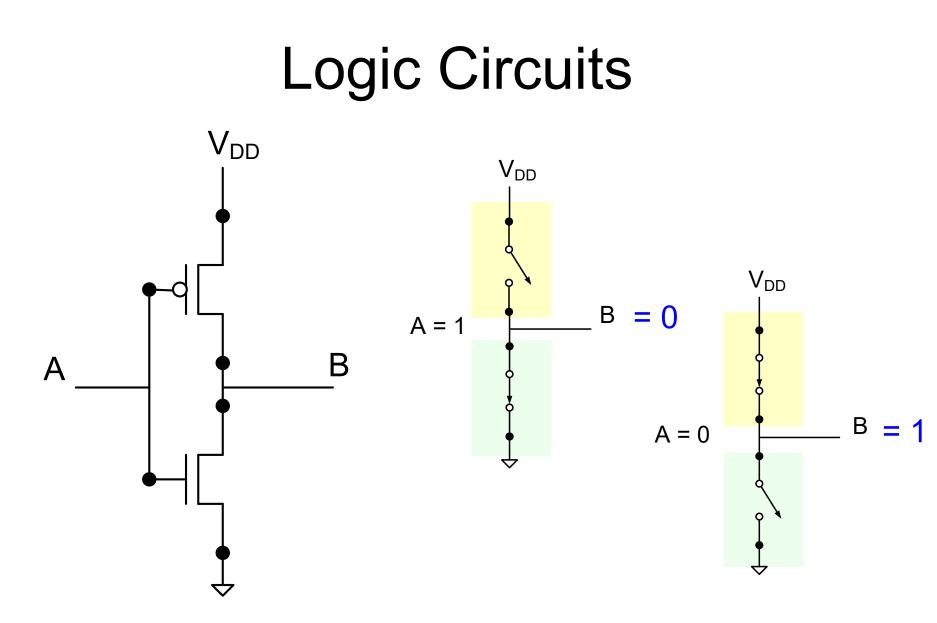
$$\begin{split} I_{D} = 0 & \text{if } |V_{GSp}| \text{is small} \quad \text{or } V_{GSp} \text{ is positive} \\ V_{DS} = 0 & \text{if } |V_{GSp}| \text{is large} \end{split}$$

### MOS Transistor Comparison of Operation

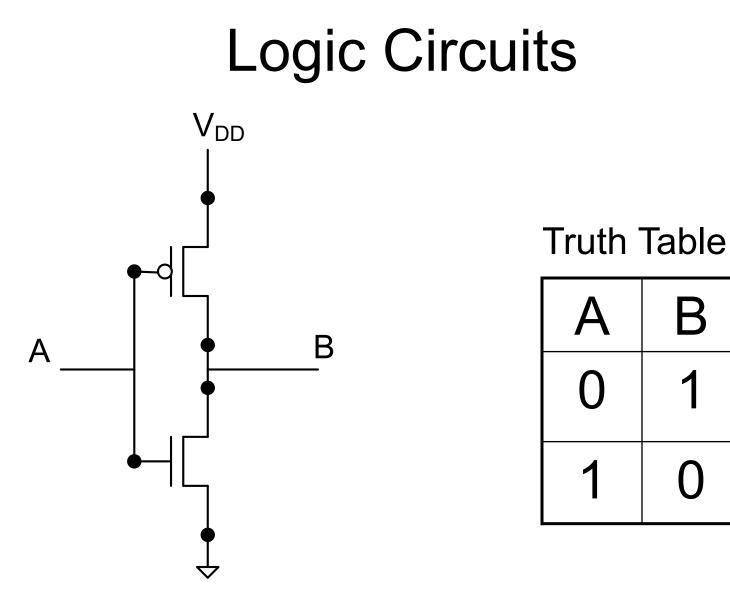


Source assumed connected to (or close to) ground

Source assumed connected to  $_{(\text{or close to})}$  positive  $V_{\text{DD}}$  and Boolean G at gate is relative to ground



**Circuit Behaves as a Boolean Inverter** 

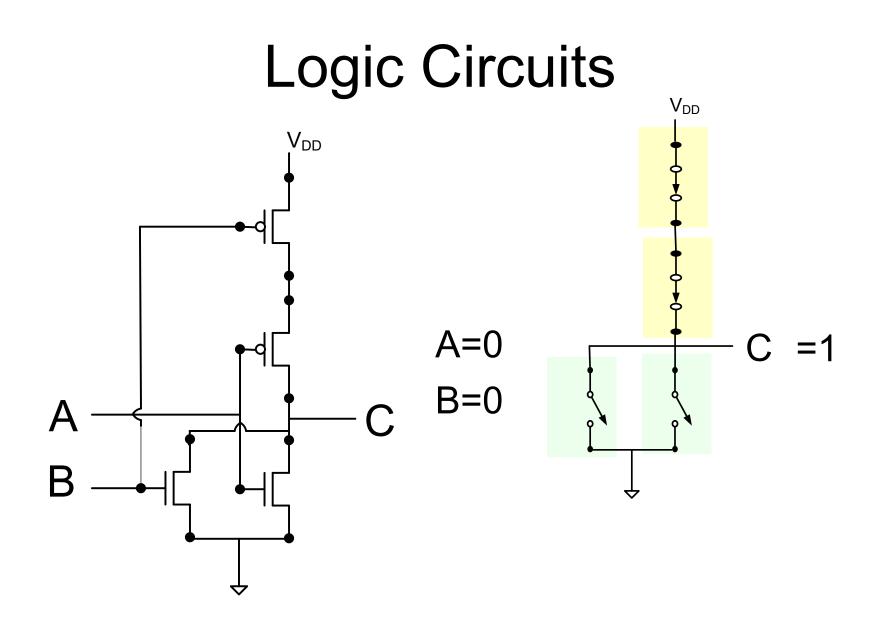


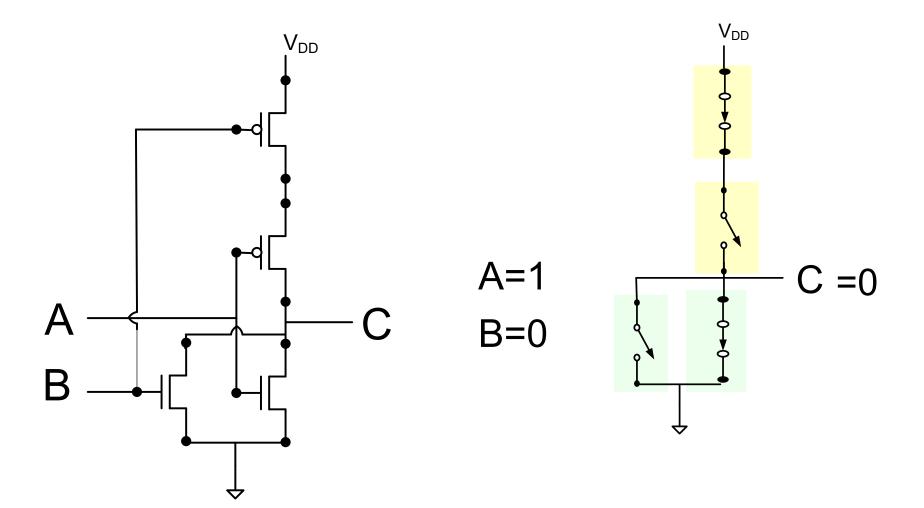
B

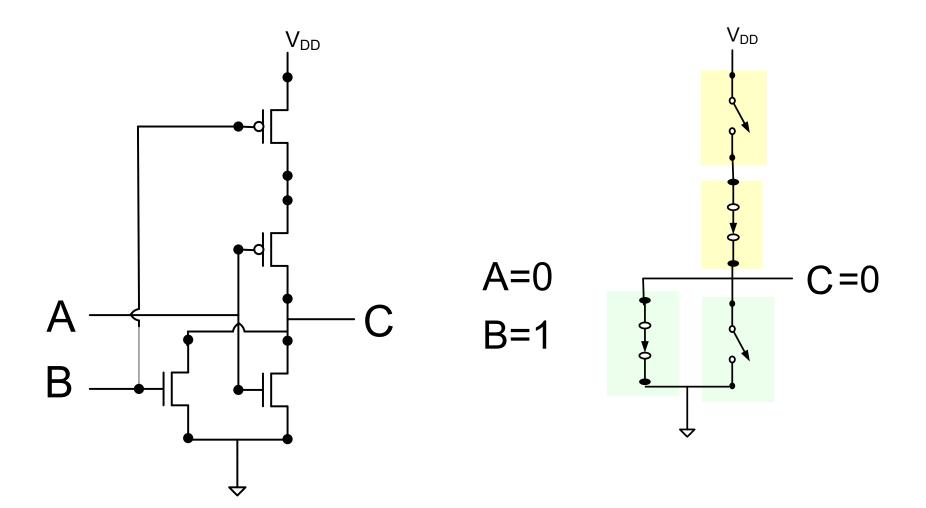
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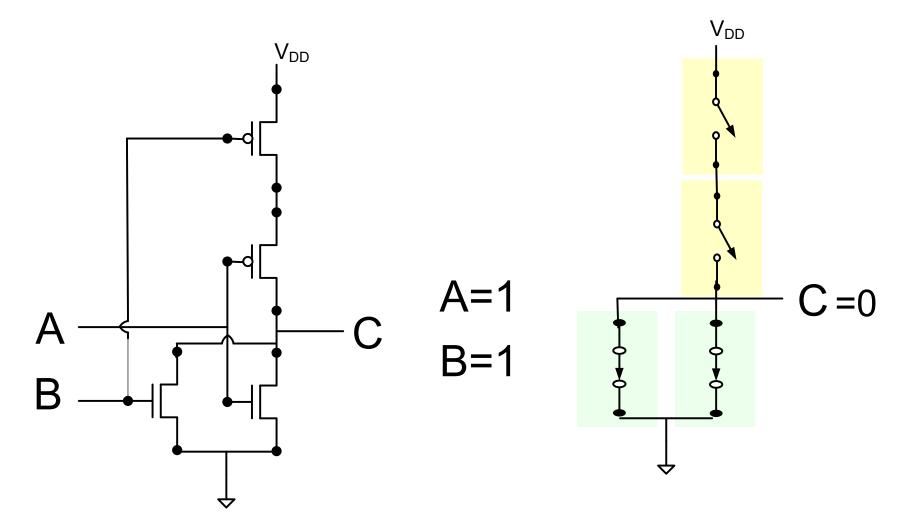
()

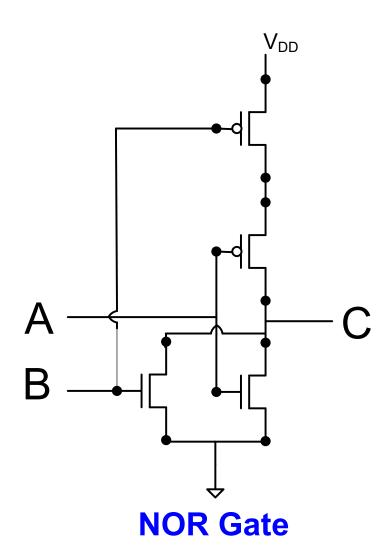
Inverter





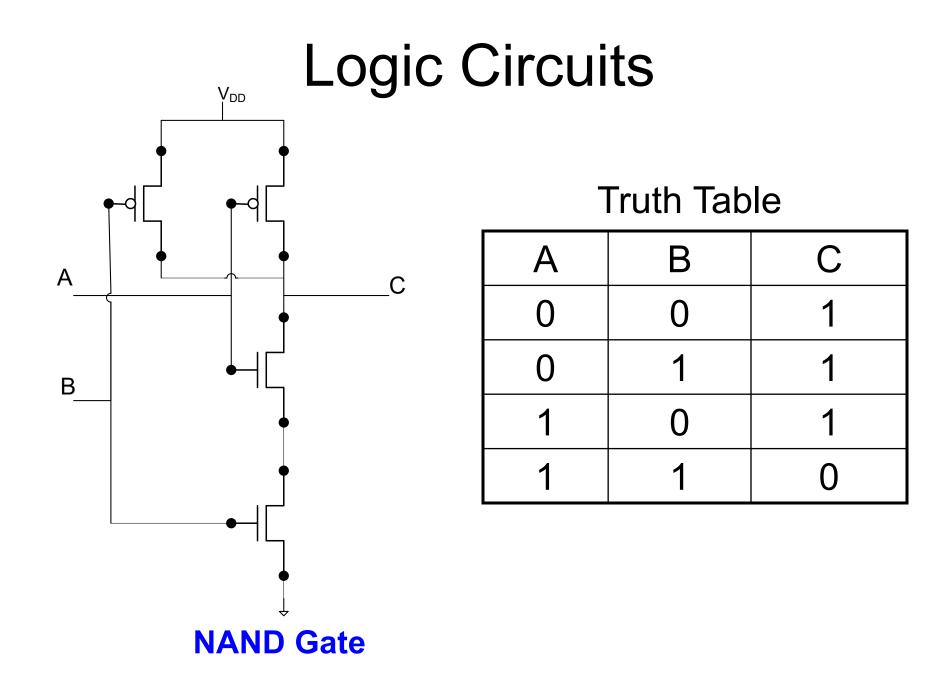






#### **Truth Table**

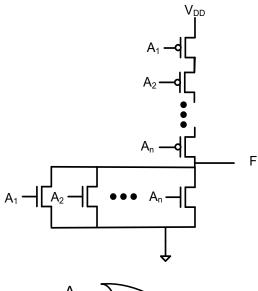
А	В	С
0	0	1
0	1	0
1	0	0
1	1	0

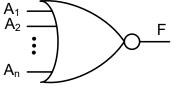


Logic Circuits

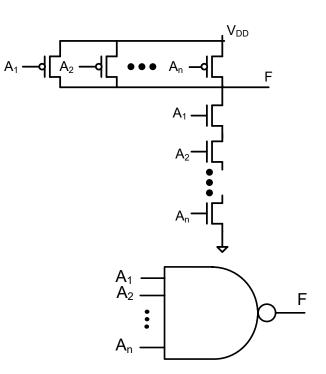
Approach can be extended to arbitrary number of inputs

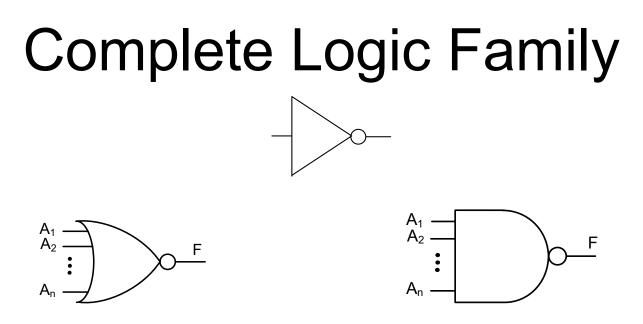
n-input NOR gate





n-input NAND gate





Family of n-input NOR gates forms a complete logic family

Family of n-input NAND gates forms a complete logic family

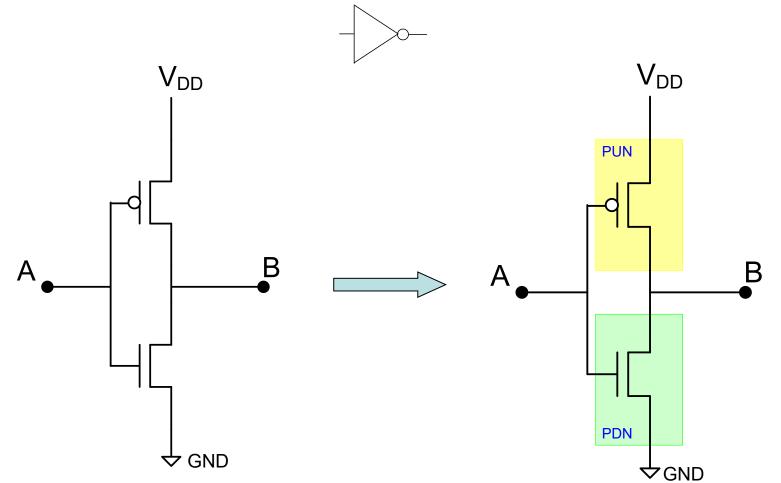
Having both NAND and NOR gates available is a luxury

Can now implement any combinational logic function !! If add one flip flop, can implement any Boolean system !!

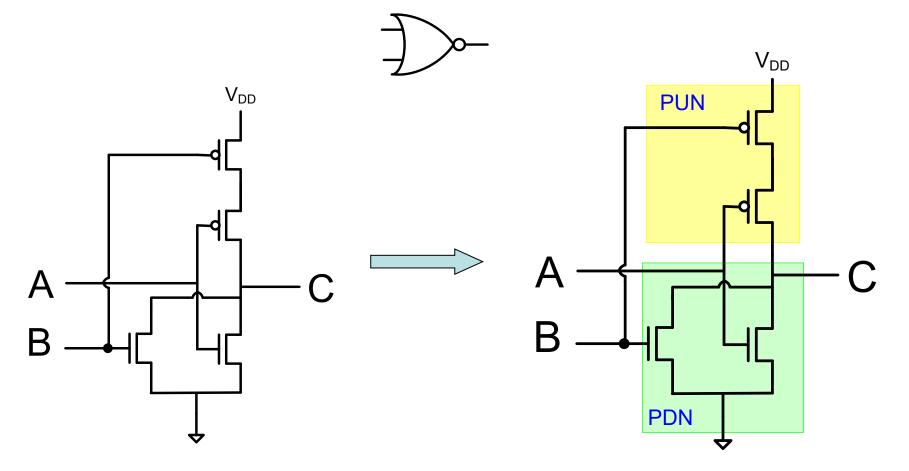
Flip flops easy to design but will discuss sequential logic systems later

# Other logic circuits

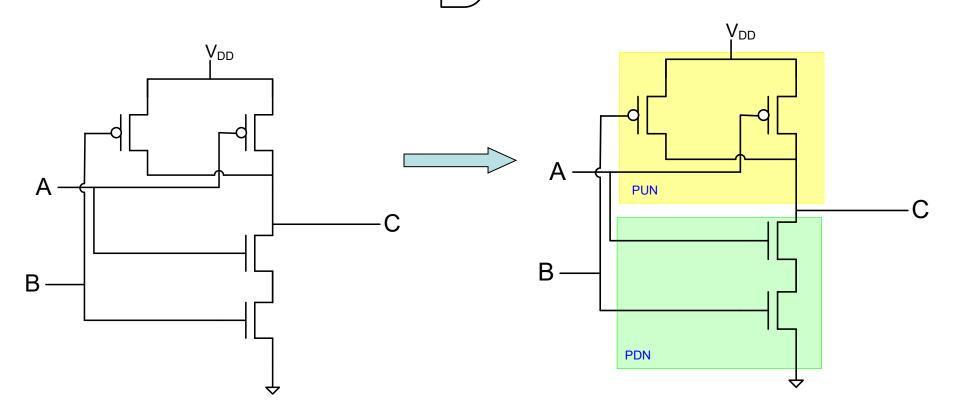
- Other methods for designing logic circuits exist
- Insight will be provided on how other logic circuits evolve
- Several different types of logic circuits are often used simultaneously in any circuit design



PU network comprised of p-channel device and "tries" to pull B to VDD when conducting PD network comprised of n-channel device and "tries to pull B to GND when conducting One and only one of these networks is conducting at the same time (to avoid contention)



PU network comprised of p-channel devices PD network comprised of n-channel devices One and only one of these networks is conducting at the same time



PU network comprised of p-channel devices

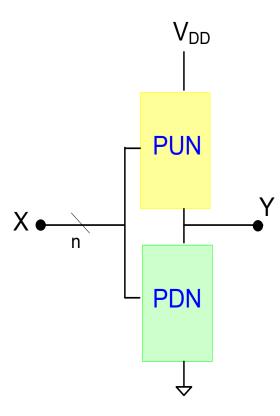
PD network comprised of n-channel devices

One and only one of these networks is conducting at the same time

In these circuits, the PUN and PDN have the 3 interesting characteristics

- 1. PU network comprised of p-channel devices
- 2. PD network comprised of n-channel devices
- 3. One and only one of these networks is conducting at the same time

What are V<sub>H</sub> and V<sub>L</sub>? What is the power dissipation? How fast are these logic circuits?





# Stay Safe and Stay Healthy !

### **End of Lecture 5**